



DDTB (LO-R1) C

PNP PRE-BIASED 500 mA SURFACE MOUNT TRANSISTOR

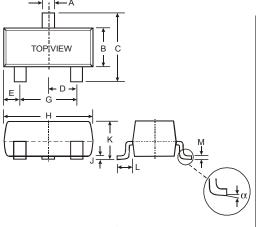
Features

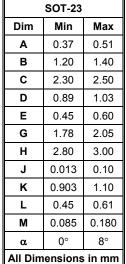
- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDTD)
- · Built-In Biasing Resistors
- Lead, Halogen and Antimony Free, RoHS Compliant "Green" Device (Notes 1 and 3)

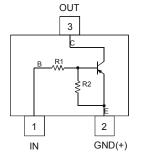
Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking Information: See Table Below & Page 3
- Ordering Information: See Page 3
- Weight: 0.008 grams (approximate)

P/N	R1 (NOM)	R2 (NOM)	Type Code
DDTB122LC	0.22KΩ	10KΩ	P75
DDTB142JC	0.47 K Ω	10KΩ	P76
DDTB122TC	0.22 K Ω	OPEN	P77
DDTB142TC	0.47ΚΩ	OPEN	P78







Schematic and Pin Diagram

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit	
Supply Voltage, (3) to (2)		Vcc	-50	V	
Input Voltage, (1) to (2)	DDTB122LC DDTB142JC	V _{IN}	+5 to -6 +5 to -6	V	
Input Voltage, (2) to (1)	DDTB122TC DDTB142TC	V _{EBO (MAX)}	-5	V	
Output Current	All	I _C	-500	mA	
Power Dissipation	(Note 2)	P _D	200	mW	
Thermal Resistance, Junction to Ambient Air	(Note 2)	$R_{ hetaJA}$	625	°C/W	
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C	

Notes:

- 1. No purposefully added lead. Halogen and Antimony Free.
- 2. Mounted on FR4 PC Board with recommended pad layout at http://www.diodes.com/datasheets/ap02001.pdf.
- Product manufactured with Data Code V9 (week 33, 2008) and newer are built with Green Molding Compound. Product manufactured prior to Date Code V9 are built with Non-Green Molding Compound and may contain Halogens or Sb₂O₃ Fire Retardants.



Electrical Characteristics @TA = 25°C unless otherwise specified R1, R2 Types

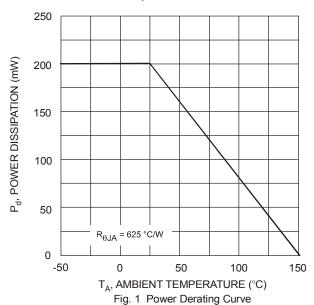
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Input Voltage	DDTB122LC DDTB142JC	V _{I(off)}	-0.3 -0.3	_	_	V	V _{CC} = -5V, I _O = -100μA
	DDTB122LC DDTB142JC			$V_O = -0.3V$, $I_O = -20mA$ $V_O = -0.3V$, $I_O = -20mA$			
Output Voltage		$V_{O(on)}$	_	_	-0.3V	V	$I_{O}/I_{I} = -50$ mA/-2.5mA
Input Current DDTB122LC DDTB142JC		l _l		_	-28 -13	mA	V _I = -5V
Output Current		I _{O(off)}	_	_	-0.5	μА	$V_{CC} = -50V, V_I = 0V$
DC Current Gain DDTB122LC DDTB142JC		G _l	56 56	_		_	V _O = -5V, I _O = -50mA
Gain-Bandwidth Product*		f⊤		200		MHz	V _{CE} = -10V, I _E = -5mA, f = 100MHz

^{*} Transistor - For Reference Only

Electrical Characteristics @TA = 25°C unless otherwise specified R1- Only Types

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	BV _{CBO}	-50	_	_	V	$I_{C} = -50 \mu A$	
Collector-Emitter Breakdown Voltage		BV _{CEO}	-40	_	_	V	I _C = -1mA
Emitter-Base Breakdown Voltage DDTB122TC DDTB142TC		BV _{EBO}	-5	_		٧	$I_E = -50\mu A$ $I_E = -50\mu A$
Collector Cutoff Current		I _{CBO}	_	_	-0.5	μА	V _{CB} = -50V
Emitter Cutoff Current DDTB122TC DDTB142TC		I _{EBO}	_	_	-0.5 -0.5	μА	V _{EB} = -4V
Collector-Emitter Saturation Voltage		V _{CE(sat)}	_	_	-0.3	V	$I_C = -50$ mA, $I_B = -2.5$ mA
DC Current Transfer Ratio DDTB122TC DDTB142TC		h _{FE}	100 100	250 250	600 600		I _C = -5mA, V _{CE} = -5V
Gain-Bandwidth Product*		f⊤	_	200		MHz	V _{CE} = -10V, I _E = 5mA, f = 100MHz

^{*} Transistor - For Reference Only



DS30403 Rev. 6 - 2 2 of 3 DDTB (LO-R1) C © Diodes Incorporated

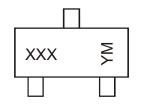


Ordering Information (Note 4)

Device	Packaging	Shipping
DDTB122LC-7-F	SOT-23	3000/Tape & Reel
DDTB142JC-7-F	SOT-23	3000/Tape & Reel
DDTB122TC-7-F	SOT-23	3000/Tape & Reel
DDTB142TC-7-F	SOT-23	3000/Tape & Reel

Notes: 4. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



XXX = Product Type Marking Code, See Table on Page 1

YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year	200)6	2007		2008		2009			2011	2012	
Code	Т		U		V W		X		Υ	Z		
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code		^	^		-	^	_	0	^	^	N.I.	_

IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.

DS30403 Rev. 6 - 2 3 of 3 DDTB (LO-R1) C © Diodes Incorporated

单击下面可查看定价,库存,交付和生命周期等信息

>>Diodes Incorporated(达尔科技)